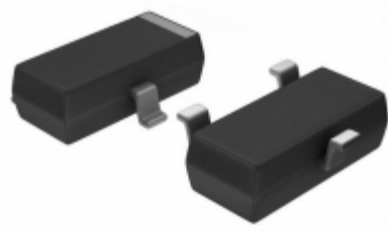










	<h2 style="color: red;">FJV3109RMTF</h2>
	Hersteller-Teilenummer: FJV3109RMTF
	Hersteller / Marke: AMI Semiconductor / ON Semiconductor
	Teil der Beschreibung: TRANS PREBIAS NPN 200MW SOT23-3
	Datenblätter: <ul style="list-style-type: none">  1.FJV3109RMTF.pdf  2.FJV3109RMTF.pdf
	RoHs Status: Bleifrei / RoHS-konform
	Lagerzustand: New original, 170150 pcs Stock Available.
	Liefern von: Hong Kong
	Versandweg: DHL/Fedex/TNT/UPS/EMS
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	FJV3109RMTF
Hersteller	AMI Semiconductor / ON Semiconductor
Beschreibung	TRANS PREBIAS NPN 200MW SOT23-3
Kategorie	Diskrete Halbleiterprodukte > Transistoren-Bipolar
Teilstatus	170150 pcs Stock
detaillierte Beschreibung	Pre-Biased Bipolar Transistor (BJT) NPN - Pre-Biased
Serie	-
Befestigungsart	Surface Mount
Leistung - max	200mW
Verpackung / Gehäuse	TO-236-3, SC-59, SOT-23-3
Supplier Device-Gehäuse	SOT-23-3 (TO-236)
Transistor-Typ	NPN - Pre-Biased
Strom - Kollektor (Ic) (max)	100mA
Spannung - Kollektor-Emitter-Durchbruch (max)	40V
VCE Sättigung (Max) @ Ib, Ic	300mV @ 1mA, 10mA
Strom - Collector Cutoff (Max)	100nA (ICBO)
DC Stromgewinn (HFE) (Min) @ Ic, VCE	100 @ 1mA, 5V
Frequenz - Übergang	250MHz
Verpackung	Tape & Reel (TR)
Widerstand - Basis (R1)	4.7 kOhms
Bleifreier Status / RoHS-Status	Lead free / RoHS Compliant
Feuchtigkeitsempfindlichkeitsniveau (MSL)	1 (Unlimited)


























FJV3109RMTF ist neu im Original, Suche FJV3109RMTF Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie FJV3109RMTF AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage FJV3109RMTF: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>FJV3110RMTF Fairchild/ON Semiconductor TRANS PREBIAS NPN 200MW SOT23-3</p>	 <p>FJV3110RMTF AMI Semiconductor / ON Semiconductor TRANS PREBIAS NPN 200MW SOT23-3</p>	 <p>FJV3111RMTF Fairchild/ON Semiconductor TRANS PREBIAS NPN 200MW SOT23-3</p>	 <p>FJV3109R FAIRCHI FJV3109R FAIRCHI</p>
 <p>FJV3108RMTF AMI Semiconductor / ON Semiconductor TRANS PREBIAS NPN 200MW SOT23-3</p>	 <p>FJV3108RMTF Fairchild/ON Semiconductor TRANS PREBIAS NPN 200MW SOT23-3</p>	 <p>FJV3109RMTF Fairchild/ON Semiconductor TRANS PREBIAS NPN 200MW SOT23-3</p>	 <p>FJV3111RMTF AMI Semiconductor / ON Semiconductor TRANS PREBIAS NPN 200MW SOT23-3</p>

heiße Teile

Mehr

 FJV1845EMTF	 FJV1845FMTF	 FJV1845FMTF	D FJV1845PMTF	 FJV1845PMTF
 FJV1845UMTF	 FJV1845UMTF	D FJV3101RLIMTF	 FJV3101RMTF	 FJV3101RMTF
 FJV3102RMTF	 FJV3102RMTF	 FJV3103RMTF	 FJV3103RMTF	 FJV3104RMTF
D FJV3104RMTF	 FJV3105RMTF	 FJV3105RMTF	 FJV3106RMTF	 FJV3106RMTF
 FJV3107RMTF	 FJV3107RMTF	 FJV3108RMTF	 FJV3108RMTF	 FJV3109R
 FJV3109RMTF	 FJV3110RMTF	D FJV3110RMTF	 FJV3111RMTF	 FJV3111RMTF
 FJV3112RMTF	D FJV3112RMTF	 FJV3113RMTF	 FJV3113RMTF	 FJV3114RMTF
 FJV3114RMTF	 FJV3115RMTF	 FJV3115RMTF	 FJV4101RMTF	 FJV4101RMTF
 FJV4102RLIMTF	 FJV4102RMTF	 FJV4102RMTF	D FJV4103RMTF	 FJV4103RMTF
 FJV4104RMTF	 FJV4104RMTF	 FJV4105RMTF	 FJV4105RMTF	 FJV4106RMTF

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